

FGW15N120VD

Discrete IGBT

Discrete IGBT (High-Speed V series)

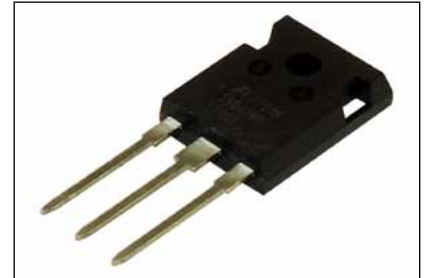
1200V / 15A

■ Features

- Low power loss
- Low switching surge and noise
- High reliability, high ruggedness (RBSOA, SCSOA etc.)

■ Applications

- Inverter for Motor drive
- AC and DC Servo drive amplifier
- Uninterruptible power supply



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at T_c=25°C unless otherwise specified)

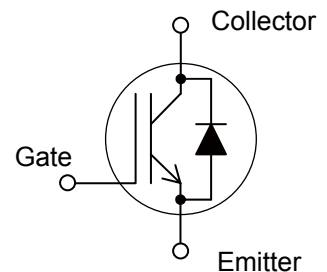
| Items | Symbols | Characteristics | Units | Remarks |
|--------------------------------|---------------------|-----------------|-------|--|
| Collector-Emitter voltage | V _{CES} | 1200 | V | |
| Gate-Emitter voltage | V _{GES} | ±20 | V | |
| DC Collector Current | I _{C@25} | 28 | A | T _c =25°C, T _j =150°C |
| | I _{C@100} | 15 | A | T _c =100°C, T _j =150°C |
| Pulsed Collector Current | I _{CP} | 30 | A | Note *1 |
| Turn-Off Safe Operating Area | - | 30 | A | V _{CE} ≤1200V, T _j ≤175°C |
| Diode Forward Current | I _{F@25} | 26 | A | |
| | I _{F@100} | 15 | A | |
| Diode Pulsed Current | I _{FP} | 30 | A | Note *1 |
| Short Circuit Withstand Time | t _{SC} | 10 | μs | V _{CC} ≤640V, V _{GE} =15V, T _j ≤150°C |
| IGBT Max. Power Dissipation | P _{D_IGBT} | 155 | W | T _c =25°C |
| FWD Max. Power Dissipation | P _{D_FWD} | 95 | W | T _c =25°C |
| Operating Junction Temperature | T _j | -40~+175 | °C | |
| Storage Temperature | T _{stg} | -55~+175 | °C | |

Note *1 : Pulse width limited by T_{jmax}.

● Electrical characteristics (at T_j= 25°C unless otherwise specified)

| Items | Symbols | Conditions | Characteristics | | | Unit | |
|--------------------------------------|-----------------------|---|-----------------------|------|------|------|----|
| | | | min. | typ. | max. | | |
| Collector-Emitter Breakdown Voltage | V _{BR(ICES)} | I _C = 50μA, V _{GE} = 0V | 1200 | - | - | V | |
| Zero Gate Voltage Collector Current | I _{CES} | V _{CE} = 1200V, V _{GE} = 0V | T _j =25°C | - | - | 250 | μA |
| | | | T _j =175°C | - | - | 2 | mA |
| Gate-Emitter Leakage Current | I _{GES} | V _{CE} = 0V, V _{GE} = ±20V | - | - | - | 200 | nA |
| Gate-Emitter Threshold Voltage | V _{GE(th)} | V _{CE} = +20V, I _C = 15mA | 6.0 | 6.5 | 7.0 | V | |
| Collector-Emitter Saturation Voltage | V _{CE(sat)} | V _{GE} = +15V, I _C = 15A | T _j =25°C | - | 1.85 | 2.4 | V |
| | | | T _j =175°C | - | 2.4 | - | |
| Input Capacitance | C _{ies} | V _{CE} =25V | - | 1015 | - | pF | |
| Output Capacitance | C _{oes} | V _{GE} =0V | - | 58 | - | | |
| Reverse Transfer Capacitance | C _{res} | f=1MHz | - | 47 | - | | |
| Gate Charge | Q _G | V _{CC} = 600V I _C = 15A V _{GE} = 15V | - | 150 | - | nC | |
| Turn-On Delay Time | t _{d(on)} | T _j = 25°C | - | 27 | - | ns | |
| Rise Time | t _r | V _{CC} = 600V | - | 20 | - | | |
| Turn-Off Delay Time | t _{d(off)} | I _C = 15A | - | 180 | - | | |
| Fall Time | t _f | V _{GE} = 15V | - | 45 | - | | |
| Turn-On Energy | E _{on} | R _G = 10Ω | - | 1.1 | - | mJ | |
| Turn-Off Energy | E _{off} | L = 500μH Energy loss include "tail" and FWD reverse recovery. | - | 0.8 | - | | |
| Turn-On Delay Time | t _{d(on)} | T _j = 175°C | - | 28 | - | ns | |
| Rise Time | t _r | V _{CC} = 600V | - | 22 | - | | |
| Turn-Off Delay Time | t _{d(off)} | I _C = 15A | - | 245 | - | | |
| Fall Time | t _f | V _{GE} = 15V | - | 75 | - | | |
| Turn-On Energy | E _{on} | R _G = 10Ω | - | 1.7 | - | mJ | |
| Turn-Off Energy | E _{off} | L = 500μH Energy loss include "tail" and FWD reverse recovery. | - | 1.4 | - | | |
| Forward Voltage Drop | V _F | I _F =15A | T _j =25°C | - | 1.7 | 2.21 | V |
| | | | T _j =175°C | - | 1.8 | - | V |
| Diode Reverse Recovery Time | t _{rr1} | V _{CC} =30V I _F = 1.5A -di/dt=200A/μs | - | 56 | 73 | ns | |
| Diode Reverse Recovery Time | t _{rr2} | V _{CC} =600V I _F =15A | - | 0.26 | - | μs | |
| Diode Reverse Recovery Charge | Q _{rr} | -di _F /dt=200A/μs T _j =25°C | - | 0.85 | - | μC | |

■ Equivalent circuit



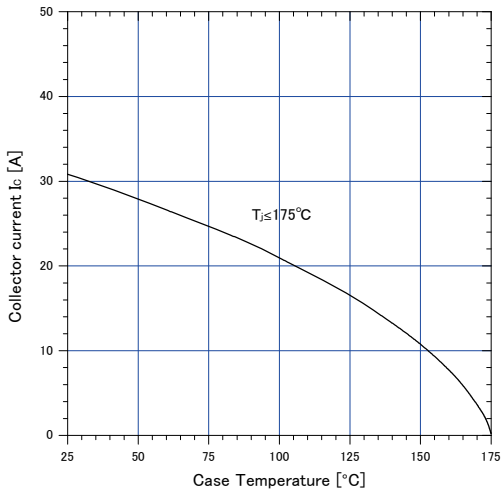
| Items | Symbols | Conditions | Characteristics | | | Unit |
|-------------------------------|-----------|--|-----------------|------|------|---------|
| | | | min. | typ. | max. | |
| Diode Reverse Recovery Time | t_{rr2} | $V_{CC}=600V$ $I_F=15A$ | - | 0.65 | - | μs |
| Diode Reverse Recovery Charge | Q_{rr} | $-di_F/dt=200A/\mu s$ $T_j=175^\circ C$ | - | 2.2 | - | μC |

● Thermal resistance

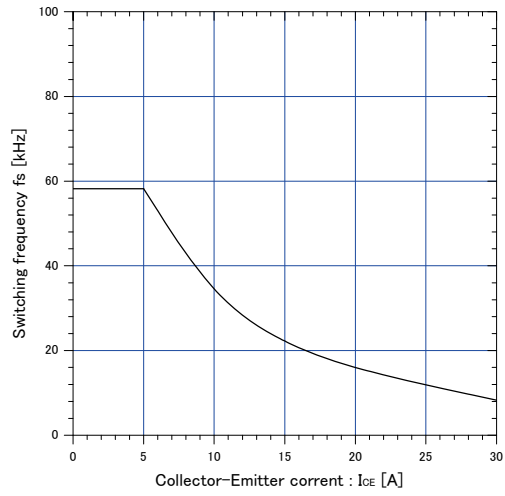
| Items | Symbols | Characteristics | | | Unit |
|---|----------------------|-----------------|------|-------|--------------|
| | | min. | typ. | max. | |
| Thermal Resistance, Junction-Ambient | $R_{th(j-a)}$ | - | - | 50 | $^\circ C/W$ |
| Thermal Resistance, IGBT Junction to Case | $R_{th(j-c)}_{IGBT}$ | - | - | 0.962 | |
| Thermal Resistance, FWD Junction to Case | $R_{th(j-c)}_{FWD}$ | - | - | 1.563 | |

■ Characteristics (Representative)

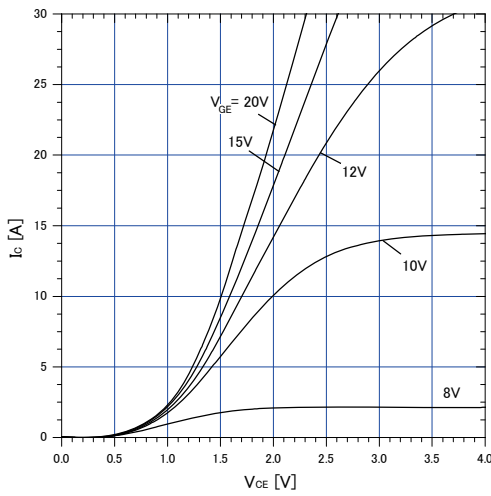
Graph.1
DC Collector Current vs T_c
 $V_{GE} \geq +15V, T_j \leq 175^\circ C$



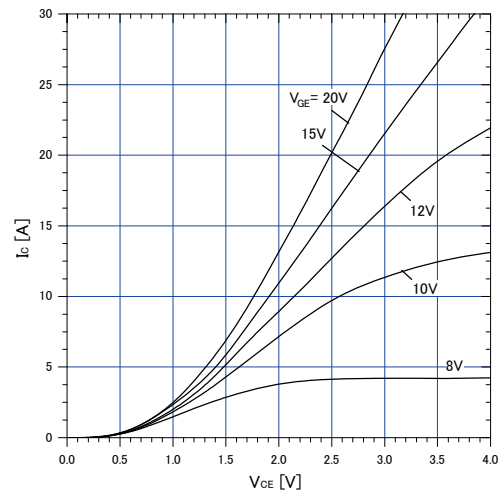
Graph.2
Collector Current vs. switching frequency
 $V_{GE} = +15V, T_c \leq 175^\circ C, V_{CC} = 600V, D = 0.5,$
 $R_g = 10\Omega, T_c = 100^\circ C$



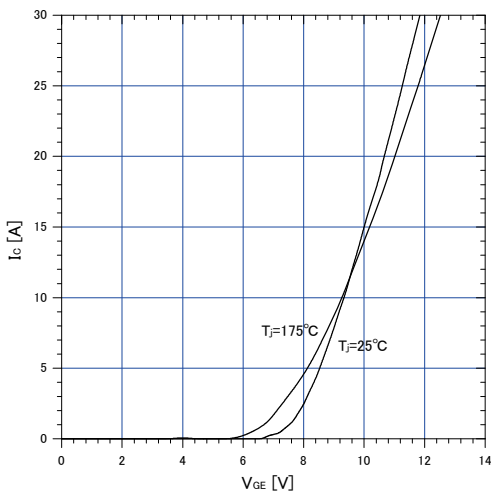
Graph.3
Typical Output Characteristics ($V_{CE} - I_c$)
 $T_j = 25^\circ C$



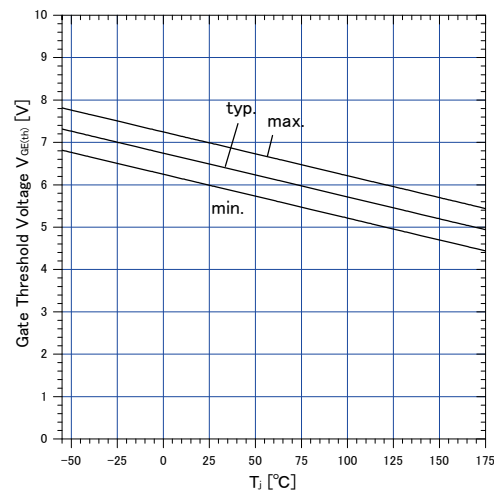
Graph.4
Typical Output Characteristics ($V_{CE} - I_c$)
 $T_j = 175^\circ C$



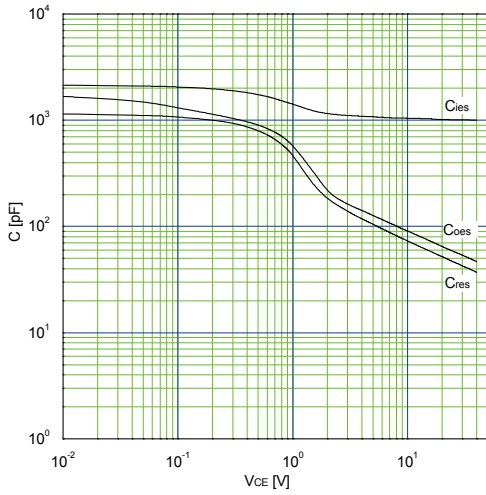
Graph.5
Typical Transfer Characteristics
 $V_{GE} = +15V$



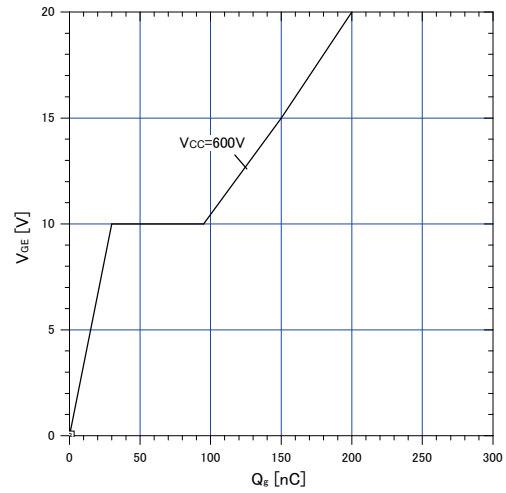
Graph.6
Gate Threshold Voltage vs. T_j
 $I_c = 15mA, V_{CE} = 20V$



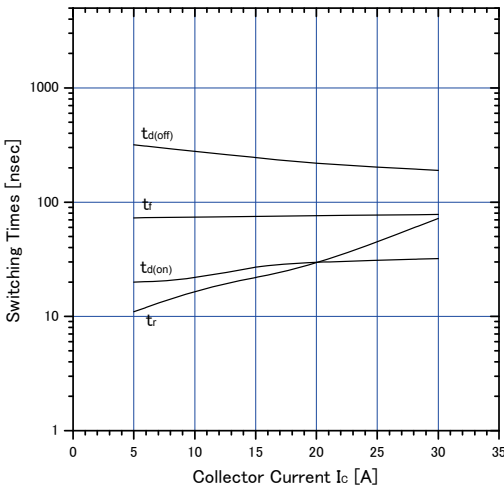
Graph.7
Typical Capacitance
 $V_{GE}=0V, f=1MHz, T_j=25^\circ C$



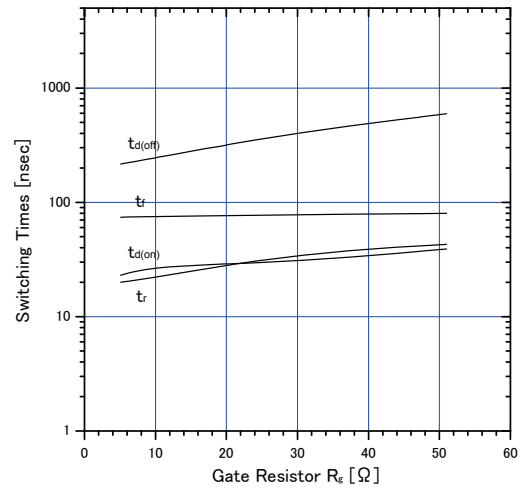
Graph.8
Typical Gate Charge
 $V_{CC}=600V, I_c=15A, T_j=25^\circ C$



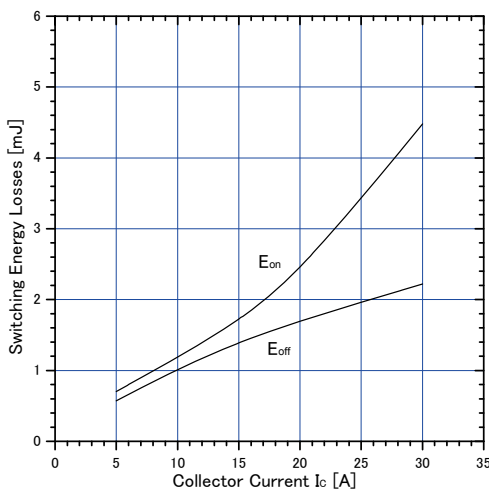
Graph.9
Typical switching time vs. I_c
 $T_j=175^\circ C, V_{CC}=600V, L=500\mu H$
 $V_{GE}=15V, R_G=10\Omega$



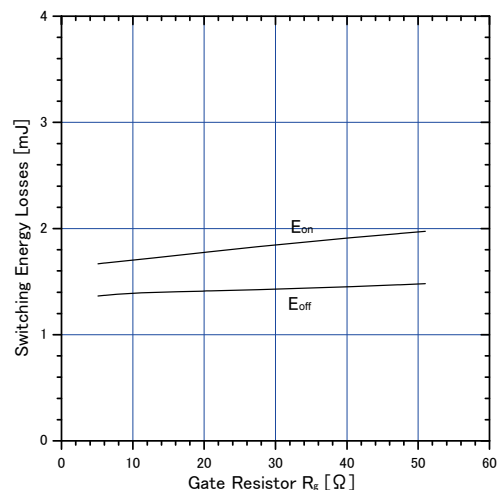
Graph.10
Typical switching time vs. R_G
 $T_j=175^\circ C, V_{CC}=600V, I_c=15A, L=500\mu H$
 $V_{GE}=15V$



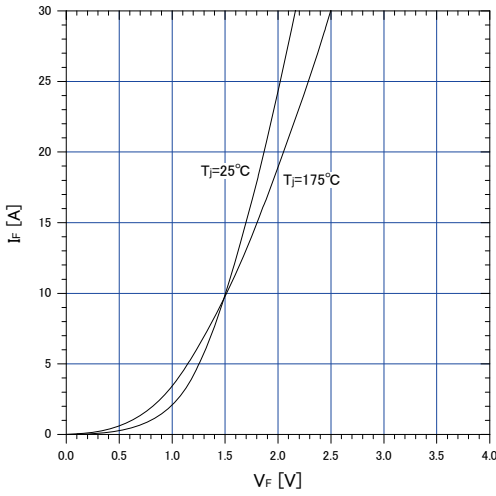
Graph.11
Typical switching losses vs. I_c
 $T_j=175^\circ C, V_{CC}=600V, L=500\mu H$
 $V_{GE}=15V, R_G=10\Omega$



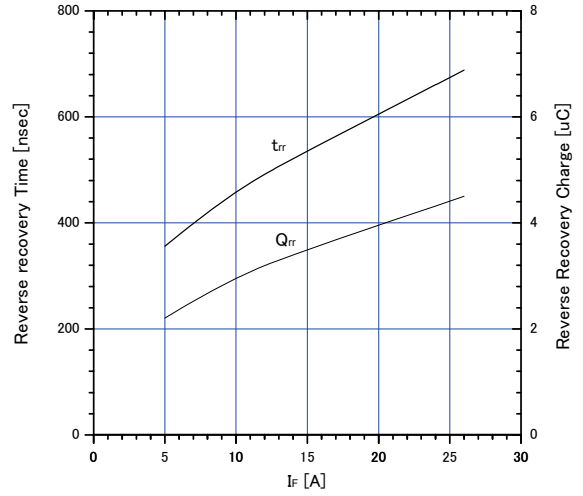
Graph.12
Typical switching losses vs. R_G
 $T_j=175^\circ C, V_{CC}=600V, I_c=15A, L=500\mu H$
 $V_{GE}=15V$



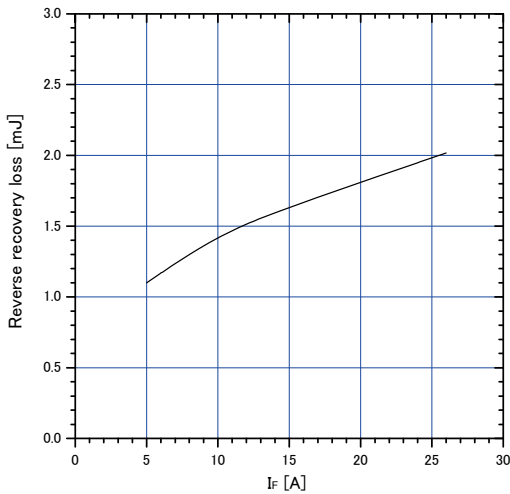
Graph.13
FWD Forward voltage drop (V_F-I_F)



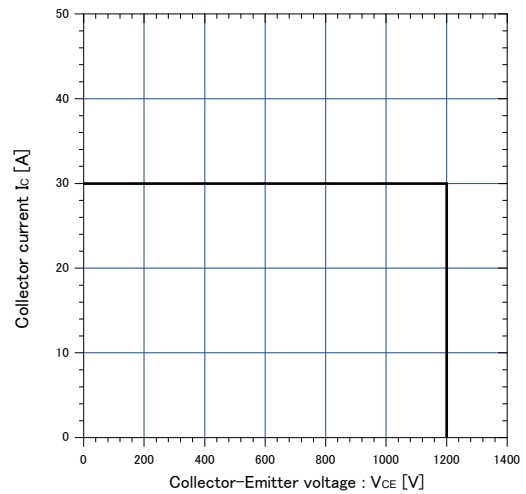
Graph.14
Typical reverse recovery characteristics vs. I_F
 $T_J=175^\circ\text{C}$, $V_{CC}=600\text{V}$, $L=500\mu\text{H}$,
 $V_{GE}=15\text{V}$, $R_G=10\Omega$



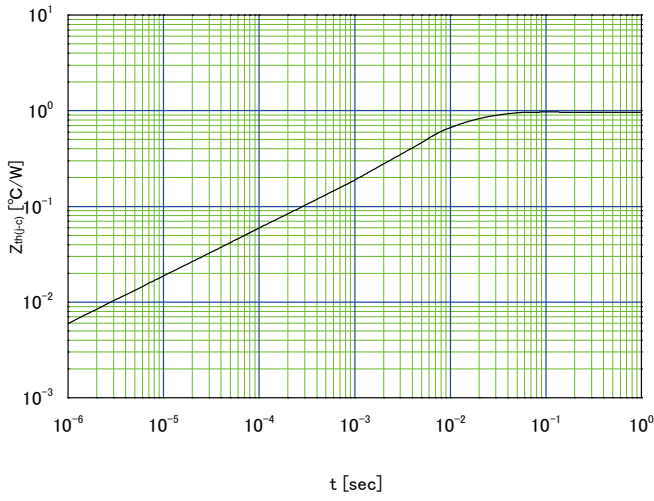
Graph.15
Typical reverse recovery loss vs. I_F
 $T_J=175^\circ\text{C}$, $V_{CC}=600\text{V}$, $L=500\mu\text{H}$
 $V_{GE}=15\text{V}$, $R_G=10\Omega$



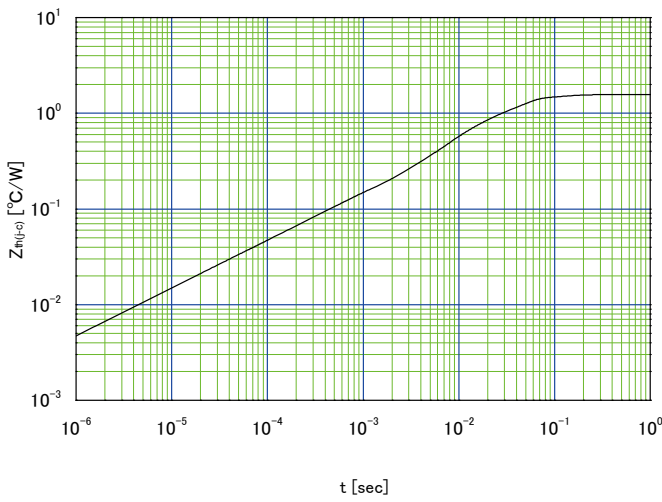
Graph.16
Reverse biased Safe Operating Area
 $T_J \leq 175^\circ\text{C}$, $V_{GE}=+15\text{V}/0\text{V}$, $R_G=10\Omega$



Graph.17
Transient thermal resistance of IGBT

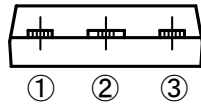
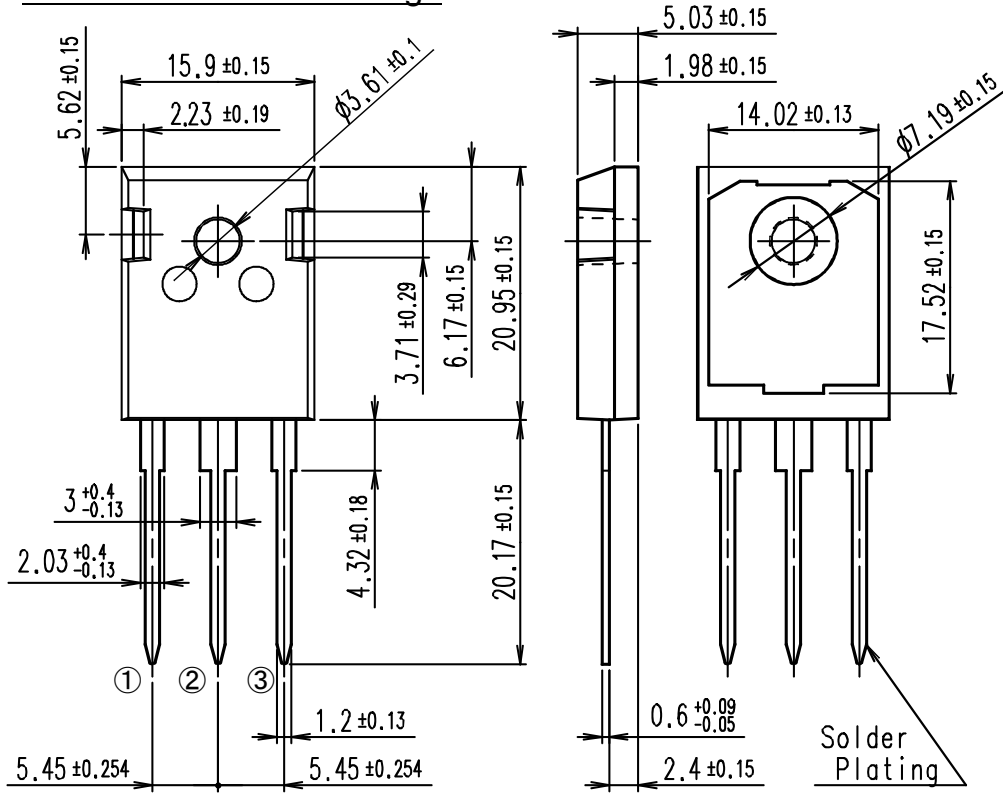


Graph.18
Transient thermal resistance of FWD



■ Outline Drawings, mm

Outview : TO-247 Package



CONNECTION

- ① GATE
- ② COLLECTOR
- ③ EMITTER

DIMENSIONS ARE IN MILLIMETERS.

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